SONY

CXD3521GG

Interface and Driver IC for LCD

Description

The CXD3521GG is an interface and driver IC for the color LCD module ACX704AKM/BKM.

Features

- Generates the color LCD module ACX704AKM/BKM drive pulse.
- Supports standby mode
- Built-in 9-channel reference voltage driver
- Built-in common voltage driver

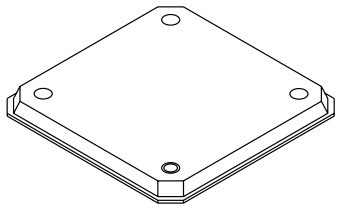
Applications

PDA, compact LCD monitor, etc.

Structure

Silicon gate CMOS IC

128 pin TFBGA (Plastic)



Absolute Maximum Ratings (Ta = 25°C)

• Supply voltage 1	V_{DD1}	V_{SS} – 0.3 to +4.6	V
• Supply voltage 2	V_{DD2}	V_{SS} – 0.3 to +6.0	V
• Input voltage	V_I	V_{SS} – 0.3 to V_{DD} + 0.3	V
• Output voltage	V_O	V_{SS} – 0.3 to V_{DD} + 0.3	V
• Storage temperature	Tstg	–55 to +125	°C

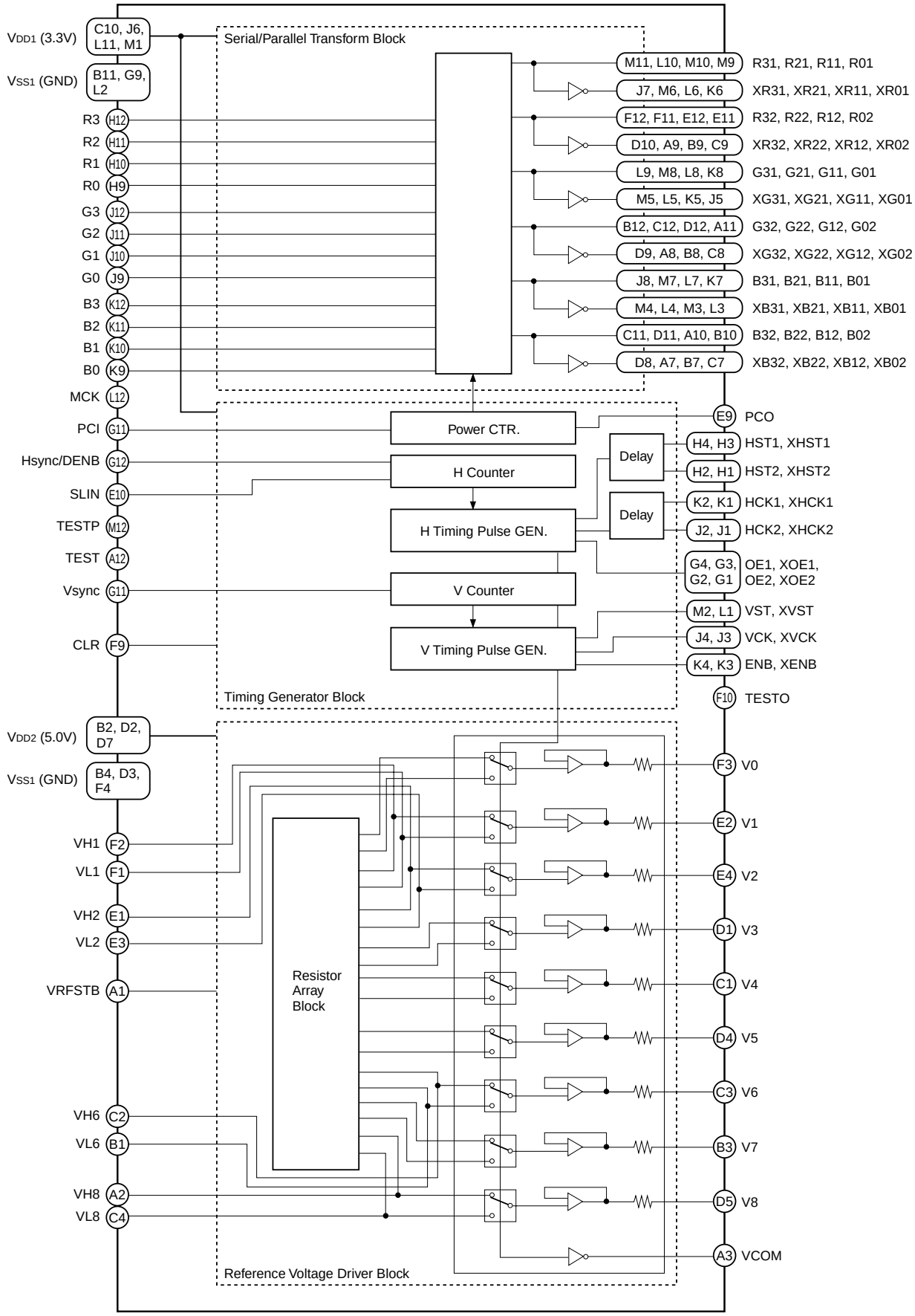
Recommended Operating Conditions

• Supply voltage 1	V_{DD1}	3.0 to 3.6	V
• Supply voltage 2	V_{DD2}	4.7 to 5.3	V
• Operating temperature	Topr	–25 to +75	°C

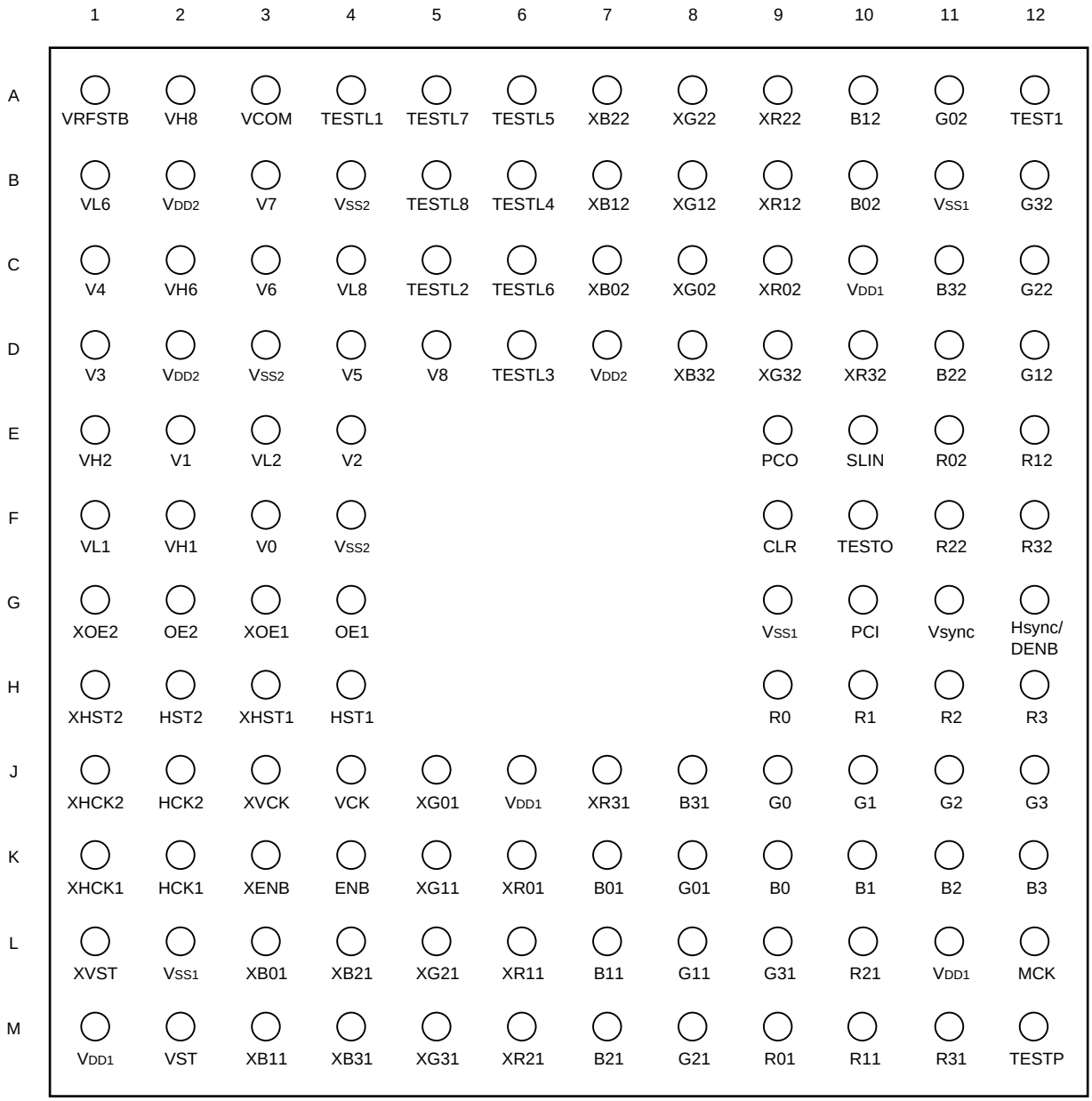
Sony reserves the right to change products and specifications without prior notice. This information does not convey any license by any implication or otherwise under any patents or other right. Application circuits shown, if any, are typical examples illustrating the operation of the devices. Sony cannot assume responsibility for any problems arising out of the use of these circuits.

E01408-PS

Block Diagram



Pin Configuration (Top View)



	1	2	3	4	5	6	7	8	9	10	11	12
A	VRFSTB	VH8	VCOM	TESTL1	TESTL7	TESTL5	XB22	XG22	XR22	B12	G02	TEST1
B	VL6	V_{DD2}	V7	V_{SS2}	TESTL8	TESTL4	XB12	XG12	XR12	B02	V_{SS1}	G32
C	V4	VH6	V6	VL8	TESTL2	TESTL6	XB02	XG02	XR02	V_{DD1}	B32	G22
D	V3	V_{DD2}	V_{SS2}	V5	V8	TESTL3	V_{DD2}	XB32	XG32	XR32	B22	G12
E	VH2	V1	VL2	V2					PCO	SLIN	R02	R12
F	VL1	VH1	V0	V_{SS2}					CLR	TESTO	R22	R32
G	XOE2	OE2	XOE1	OE1					V_{SS1}	PCI	Vsync	Hsync/ DENB
H	XHST2	HST2	XHST1	HST1					R0	R1	R2	R3
J	XHCK2	HCK2	XVCK	VCK	XG01	V_{DD1}	XR31	B31	G0	G1	G2	G3
K	XHCK1	HCK1	XENB	ENB	XG11	XR01	B01	G01	B0	B1	B2	B3
L	XVST	V_{SS1}	XB01	XB21	XG21	XR11	B11	G11	G31	R21	V_{DD1}	MCK
M	V_{DD1}	VST	XB11	XB31	XG31	XR21	B21	G21	R01	R11	R31	TESTP

Pin Description

Pin No.	Symbol	I/O	Description	Input pin for open status
B11	V_{SS1}	—	GND (Logic)	—
G9	V_{SS1}	—	GND (Logic)	—
L2	V_{SS1}	—	GND (Logic)	—
C10	V_{DD1}	—	Power supply (3.3V)	—
J6	V_{DD1}	—	Power supply (3.3V)	—
L11	V_{DD1}	—	Power supply (3.3V)	—
M1	V_{DD1}	—	Power supply (3.3V)	—
F9	CLR	I	System reset (Cleared at 0V)	UP*
H12	R3	I	Red signal input (MSB)	—
H11	R2	I	Red signal input	—
H10	R1	I	Red signal input	—
H9	R0	I	Red signal input (LSB)	—
J12	G3	I	Green signal input (MSB)	—
J11	G2	I	Green signal input	—
J10	G1	I	Green signal input	—
J9	G0	I	Green signal input (LSB)	—
K12	B3	I	Blue signal input (MSB)	—
K11	B2	I	Blue signal input	—
K10	B1	I	Blue signal input	—
K9	B0	I	Blue pulse input (LSB)	—
G12	Hsync/DENB	I	Hsync pulse input/Data enable signal input	—
G11	Vsync	I	Vsync pulse input	—
L12	MCK	I	Dot clock input	—
G10	PCI	I	Power control signal input	—
E10	SLIN	I	Sync input signal mode selector switch	—
F10	TESTO	O	Test output (Leave it open.)	—
E9	PCO	O	Power control signal output	—
M11	R31	O	Red signal output	—
L10	R21	O	Red signal output	—
M10	R11	O	Red signal output	—
M9	R01	O	Red signal output	—
L9	G31	O	Green signal output	—
M8	G21	O	Green signal output	—
L8	G11	O	Green signal output	—
K8	G01	O	Green signal output	—
J8	B31	O	Blue signal output	—

* UP: Pull-up (typ. 160kΩ)

Pin No.	Symbol	I/O	Description	Input pin for open status
M7	B21	O	Blue signal output	—
L7	B11	O	Blue signal output	—
K7	B01	O	Blue signal output	—
J7	XR31	O	R31 signal inversion output	—
M6	XR21	O	R21 signal inversion output	—
L6	XR11	O	R11 signal inversion output	—
K6	XR01	O	R01 signal inversion output	—
M5	XG31	O	G31 signal inversion output	—
L5	XG21	O	G21 signal inversion output	—
K5	XG11	O	G11 signal inversion output	—
J5	XG01	O	G01 signal inversion output	—
M4	XB31	O	B31 signal inversion output	—
L4	XB21	O	B21 signal inversion output	—
M3	XB11	O	B11 signal inversion output	—
L3	XB01	O	B01 signal inversion output	—
M12	TESTP	I	Test input (Connect to GND.)	—
A12	TEST	I	Test input (Connect to GND.)	DWN*
M2	VST	O	VST pulse output	—
L1	XVST	O	VST pulse inversion output	—
K4	ENB	O	ENB pulse output	—
K3	XENB	O	ENB pulse inversion output	—
J4	VCK	O	VCK pulse output	—
J3	XVCK	O	VCK pulse inversion output	—
K2	HCK1	O	HCK1 pulse output	—
K1	XHCK1	O	HCK1 pulse inversion output	—
J2	HCK2	O	HCK2 pulse output	—
J1	XHCK2	O	HCK2 pulse inversion output	—
H4	HST1	O	HST1 pulse output	—
H3	XHST1	O	HST1 pulse inversion output	—
H2	HST2	O	HST2 pulse output	—
H1	XHST2	O	HST2 pulse inversion output	—
G4	OE1	O	OE1 pulse output	—
G3	XOE1	O	OE1 pulse inversion output	—
G2	OE2	O	OE2 pulse output	—
G1	XOE2	O	OE2 pulse inversion output	—
D8	XB32	O	B32 signal inversion output	—
A7	XB22	O	B22 signal inversion output	—

* DWN: Pull-down (typ. 180kΩ)

Pin No.	Symbol	I/O	Description	Input pin for open status
B7	XB12	O	B12 signal inversion output	—
C7	XB02	O	B02 signal inversion output	—
D9	XG32	O	G32 signal inversion output	—
A8	XG22	O	G22 signal inversion output	—
B8	XG12	O	G12 signal inversion output	—
C8	XG02	O	G02 signal inversion output	—
D10	XR32	O	R32 signal inversion output	—
A9	XR22	O	R22 signal inversion output	—
B9	XR12	O	R12 signal inversion output	—
C9	XR02	O	R02 signal inversion output	—
C11	B32	O	Blue signal output	—
D11	B22	O	Blue signal output	—
A10	B12	O	Blue signal output	—
B10	B02	O	Blue signal output	—
B12	G32	O	Green signal output	—
C12	G22	O	Green signal output	—
D12	G12	O	Green signal output	—
A11	G02	O	Green signal output	—
F12	R32	O	Red signal output	—
F11	R22	O	Red signal output	—
E12	R12	O	Red signal output	—
E11	R02	O	Red signal output	—
B4	V_{SS2}	—	GND (Analog)	—
D3	V_{SS2}	—	GND (Analog)	—
F4	V_{SS2}	—	GND (Analog)	—
B2	V_{DD2}	—	Power supply (5.0V)	—
D2	V_{DD2}	—	Power supply (5.0V)	—
D7	V_{DD2}	—	Power supply (5.0V)	—
A4	TESTL1	O	Test output (Leave it open.)	—
C5	TESTL2	O	Test output (Leave it open.)	—
D6	TESTL3	I	Test input (Connect to GND.)	DWN*
B6	TESTL4	I	Test input (Connect to GND.)	—
A6	TESTL5	O	Test output (Leave it open.)	—
A5	TESTL6	I	Test input (Connect to GND.)	—
C6	TESTL7	I	Test input (Connect to GND.)	—
B5	TESTL8	I	Test input (Connect to GND.)	—
F3	V0	O	V0 output	—

* DWN: Pull-down (typ. 180kΩ)

Pin No.	Symbol	I/O	Description	Input pin for open status
E2	V1	O	V1 output	—
E4	V2	O	V2 output	—
D1	V3	O	V3 output	—
C1	V4	O	V4 output	—
D4	V5	O	V5 output	—
C3	V6	O	V6 output	—
B3	V7	O	V7 output	—
D5	V8	O	V8 output	—
A3	VCOM	O	VCOM output	—
A1	VRFSTB	I	Reference voltage driver on/off selector switch	DWN*
F2	VH1	I	VH1 input	—
F1	VL1	I	VL1 input	—
E1	VH2	I	VH2 input	—
E3	VL2	I	VL2 input	—
C2	VH6	I	VH6 input	—
B1	VL6	I	VL6 input	—
A2	VH8	I	VH8 input	—
C4	VL8	I	VL8 input	—

* DWN: Pull-down (typ. 180kΩ)

Electrical Characteristics (Serial/parallel conversion block, timing generator block)

DC Characteristics (V_{DD1} = 3.0 to 3.6V, Ta = –25 to +75°C)

Item	Symbol	Applicable pins	Conditions	Min.	Typ.	Max.	Unit
Supply voltage	V_{DD1}	V_{DD1}	—	3.0	3.3	3.6	V
Current consumption	I_{DD1}	V_{DD1}	No load, Ta = 25°C V_{DD1} = 3.3V, MCK: 5.62MHz	—	1.5	—	mA
Input voltage 1	V_{IH1}	MCK, VRFSTB, TESTL1, TESTL2, TESTL3, TESTL4	CMOS input cell	0.7V_{DD1}	—	—	V
	V_{IL1}			—	—	0.2V_{DD1}	
Input voltage 2	Vt_+	All input pins excluding MCK, VRFSTB, TESTL1, TESTL2, TESTL3, TESTL4	CMOS Schmitt trigger input cell	—	—	0.75V_{DD1}	V
	Vt_-			0.15V_{DD1}	—	—	
Input current 1	$\lvert I_{IL1} \rvert$	R0, R1, R2, R3, G0, G1, G2, G3, B0, B1, B2, B3, Hsync/DENB, Vsync, MCK, PCI	V_I = 0V	—	—	1.0	µA
	$\lvert I_{IH1} \rvert$		V_I = V_{DD}	—	—	1.0	
Input current 2	$\lvert I_{IL2} \rvert$	CLR	V_I = 0V	10	—	100	µA
	$\lvert I_{IH2} \rvert$		V_I = V_{DD}	—	—	3.0	
Input current 3	$\lvert I_{IL3} \rvert$	TEST, TESTP, SLIN	V_I = 0V	—	—	3.0	µA
	$\lvert I_{IH3} \rvert$		V_I = V_{DD}	10	—	100	
Output voltage 1	V_{OL1}	R01, R11, R21, R31, R02, R12, R22, R32, XR01, XR11, XR21, XR31, XR02, XR12, XR22, XR32, G01, G11, G21, G31, G02, G12, G22, G32, XG01, XG11, XG21, XG31, XG02, XG12, XG22, XG32, B01, B11, B21, B31, B02, B12, B22, B32, XB01, XB11, XB21, XB31, XB02, XB12, XB22, XB32, VST, XVST, ENB, XENB, OE1, XOE1, OE2, XOE2, TESTO	I_{OL1} = 4.0mA	—	—	0.2	V
	V_{OH1}		I_{OH1} = –4.0mA	V_{DD} – 0.8	—	—	
Output voltage 2	V_{OL2}	HST1, XHST1, HST2, XHST2, VCK, XVCK, PCO	I_{OL2} = 6.0mA	—	—	0.2	V
	V_{OH2}		I_{OH2} = –6.0mA	V_{DD} – 0.8	—	—	
Output voltage 3	V_{OL3}	HCK1, XHCK1, HCK2, XHCK2	I_{OL3} = 10.0mA	—	—	0.4	V
	V_{OH3}		I_{OH3} = –10.0mA	V_{DD} – 0.8	—	—	

AC Characteristics (V_{DD} = 3.0 to 3.6V, Ta = –25 to +75°C)

Item	Symbol	Applicable pins	Conditions*1	Min.	Typ.	Max.	Unit
HCK/HST time difference	$\Delta t_{HST-HCKU}$ $\Delta t_{HST-HCKD}$	HCK1, HCK2, XHCK1, XHCK2, HST1, HST2, XHST1, XHST2	—	—	—	15*2	ns
Data output rise time	t_{RD}	R01, R11, R21, R31, R02, R12, R22, R32, XR01, XR11, XR21, XR31, XR02, XR12, XR22, XR32, G01, G11, G21, G31, G02, G12, G22, G32, XG01, XG11, XG21, XG31, XG02, XG12, XG22, XG32, B01, B11, B21, B31, B02, B12, B22, B32, XB01, XB11, XB21, XB31, XB02, XB12, XB22, XB32	GND – V_{DD} (0 – 90%)	—	—	35	ns
Data output fall time	t_{FD}		V_{DD} – GND (100 – 10%)	—	—	35	
Horizontal pulse output rise time	t_{RHP}	HCK1, HCK2, XHCK1, XHCK2, HST1, HST2, XHST1, XHST2	GND – V_{DD} (0 – 90%)	—	—	35	ns
Horizontal pulse output fall time	t_{FHP}		V_{DD} – GND (100 – 10%)	—	—	35	
Vertical pulse output rise time	t_{RVP}	VCK, XVCK, VST, XVST, ENB, XENB, OE1, OE2, XOE1, XOE2, PCO, TESTO	GND – V_{DD} (0 – 90%)	—	—	50	ns
Vertical pulse output fall time	t_{FVP}		V_{DD} – GND (100 – 10%)	—	—	50	
HCK1, HCK2, XHCK1, XHCK2/ DATA setup time	t_{STP}	HCK1, HCK2, XHCK1, XHCK2, R01, R11, R21, R31, R02, R12, R22, R32, XR01, XR11, XR21, XR31, XR02, XR12, XR22, XR32, G01, G11, G21, G31, G02, G12, G22, G32, XG01, XG11, XG21, XG31, XG02, XG12, XG22, XG32, B01, B11, B21, B31, B02, B12, B22, B32, XB01, XB11, XB21, XB31, XB02, XB12, XB22, XB32	*3	35	55	100	ns
HCK, VCK duty	dHCK dVCK	HCK1, HCK2, XHCK1, XHCK2, VCK, XVCK	*4	48	50	52	%

*1 Load capacitance CL of each output pin is shown below.
- R01, R11, R21, R31, R02, R12, R22, R32, XR01, XR11, XR21, XR31, XR02, XR12, XR22, XR32, G01, G11, G21, G31, G02, G12, G22, G32, XG01, XG11, XG21, XG31, XG02, XG12, XG22, XG32, B01, B11, B21, B31, B02, B12, B22, B32, XB01, XB11, XB21, XB31, XB02, XB12, XB22, XB32, OE1, XOE1, OE2, XOE2, TESTO, ENB, XENB : CL = 70pF
- HCK1, HCK2, XHCK1, XHCK2 : CL = 180pF
- VCK, XVCK : CL = 150pF
- HST1, HST2, XHST1, XHST2, VST, XVST, PCO : CL = 100pF

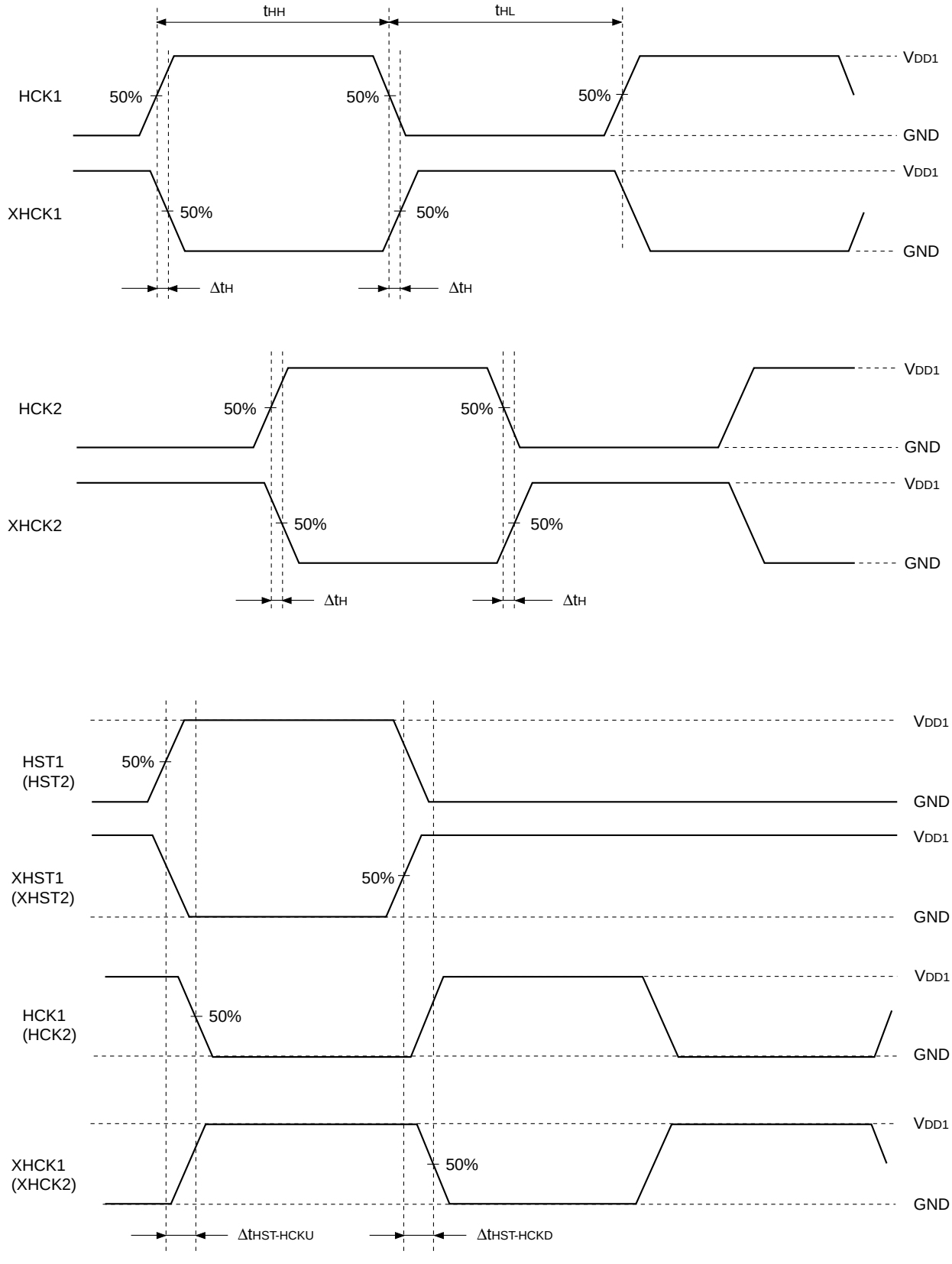
*2 Absolute value of the time difference of the change point at HST1, XHST1, HCK1 and XHCK1 (50%) is within 15ns.
Similarly, absolute value of the time difference of the change point at HST2, XHST2, HCK2 and XHCK2 (50%) is within 15ns.

*3 t_{STP}: t_{ST1D}, t_{ST1U}, t_{ST2D}, t_{ST2U}

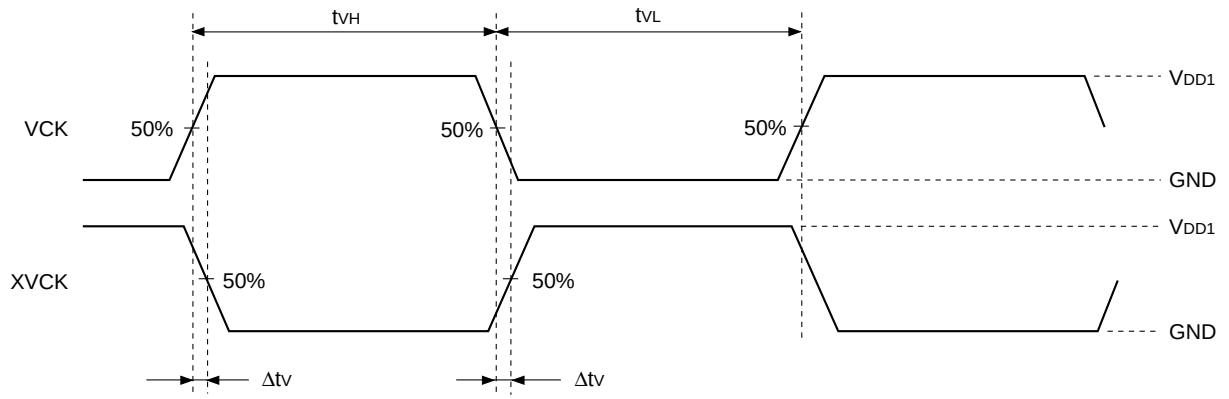
*4 dHCK = $(t_{HH}/(t_{HH} + t_{HL})) \times 100$, dVCK = $(t_{VH}/(t_{VH} + t_{VL})) \times 100$

Timing Definition

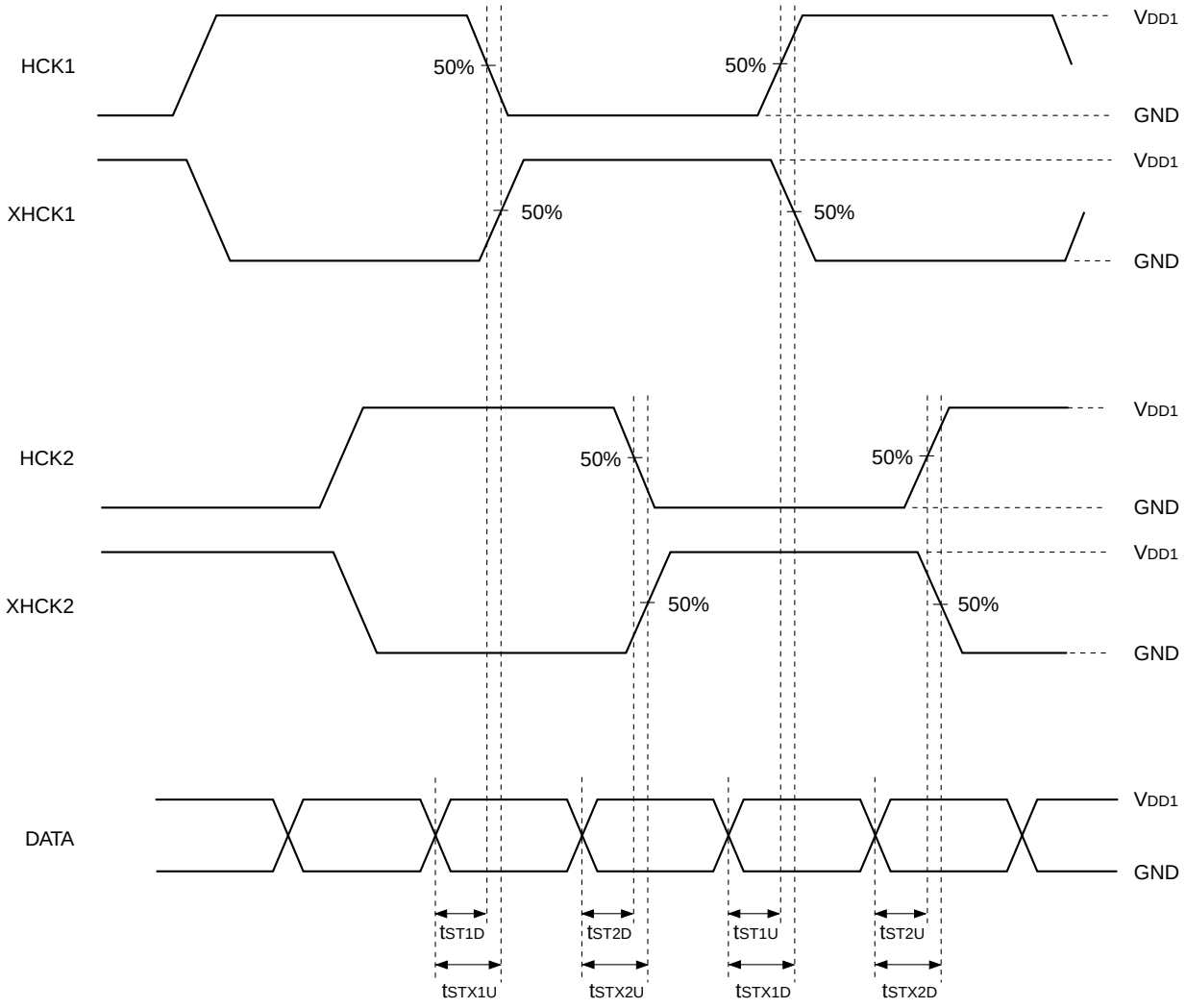
Horizontal System



Vertical System



DATA

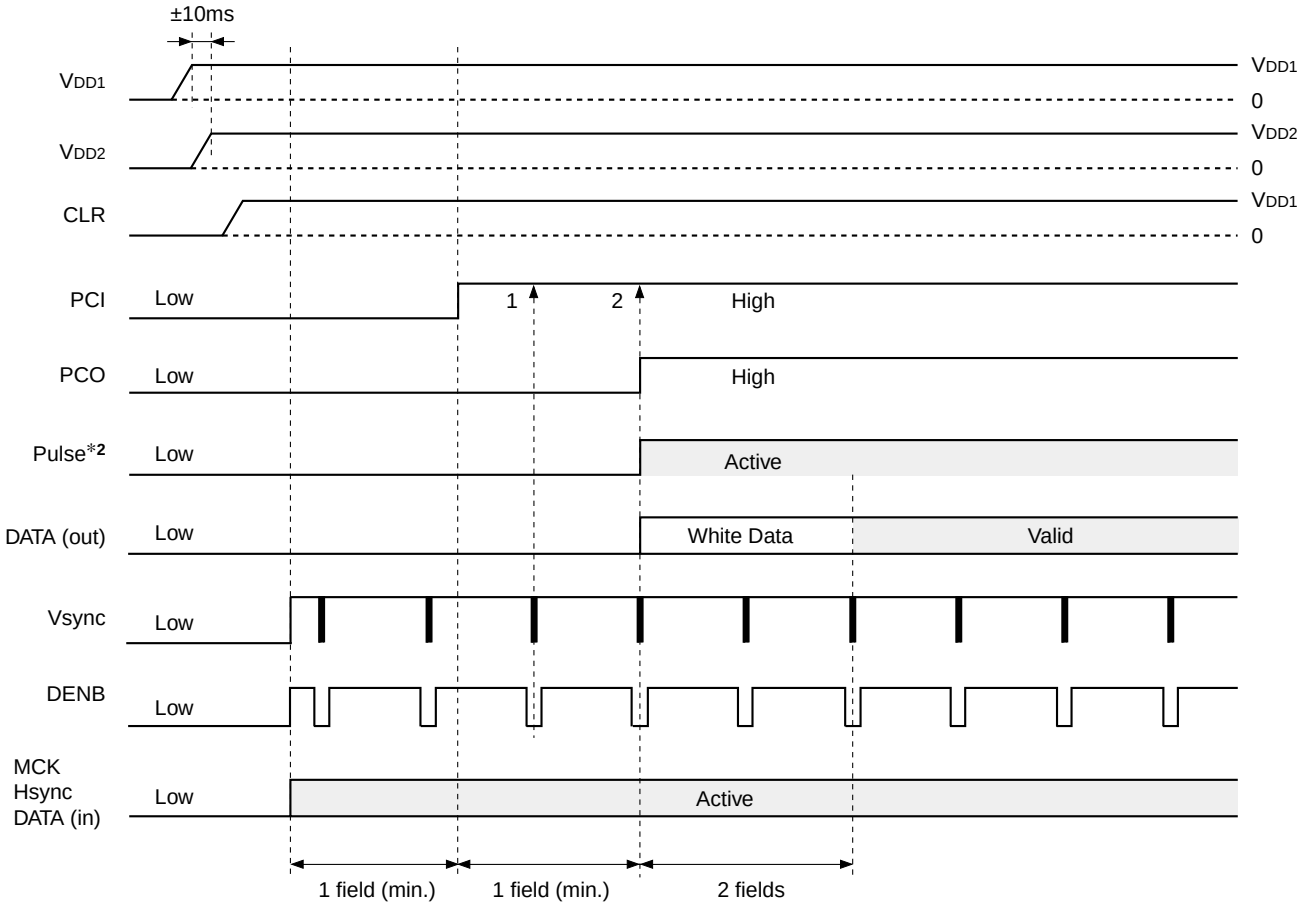


PCI, PCO

These pins control to turn power on/off of the ACX704AKM/BKM when the LCD is turned on/off. Connect PCO to DC-DC converter that can control power on/off of the ACX704AKM/BKM.

Power-on Sequence

- Raise and fall V_{DD1} and V_{DD2} simultaneously (within 10ms)
- Input the input signal*1 for 1 field (Min.), and then raise PCI.
- After PCI becomes high, latch is performed twice at Vsync. When both of them are high, PCO output is changed from low to high.
  (Turn the power on of the ACX704AKM/BKM at this timing.)
  Also, effective screen is displayed after two fields of entire white display from this timing.

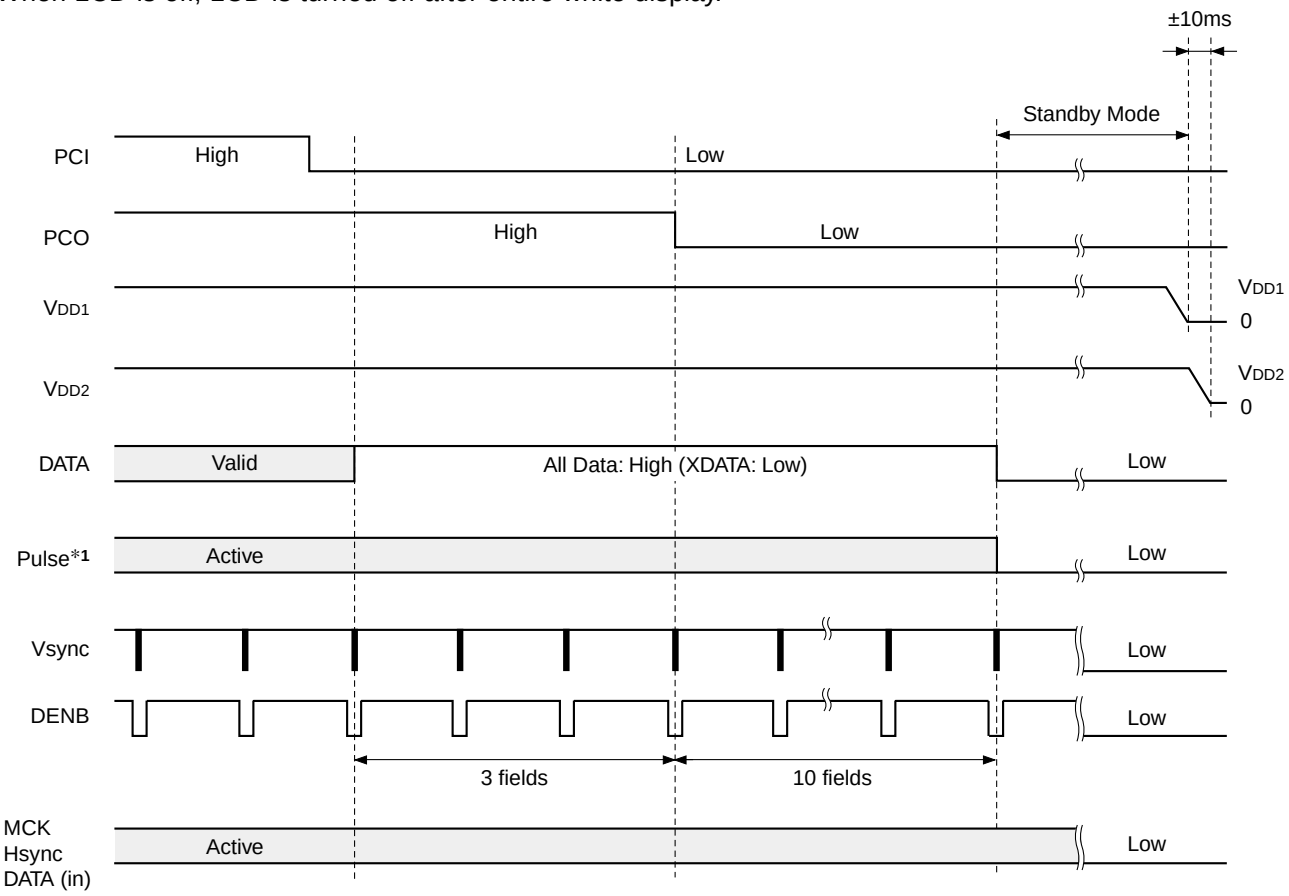


*1 Hsync, Vsync, DENB, MCK, DATA

*2 HST1, XHST1, HST2, XHST2, HCK1, XHCK1, HCK2, XHCK2, VST, XVST, VCK, XVCK, ENB, XENB, OE1, XOE1, OE2, XOE2, TESTO, (FRP)

Power-off Sequence (Standby)

• When LCD is off, LCD is turned off after entire white display.



*1 HST1, XHST1, HST2, XHST2, HCK1, XHCK1, HCK2, XHCK2, VST, XVST, VCK, XVCK, ENB, XENB, OE1, XOE1, OE2, XOE2, TESTO, (FRP)

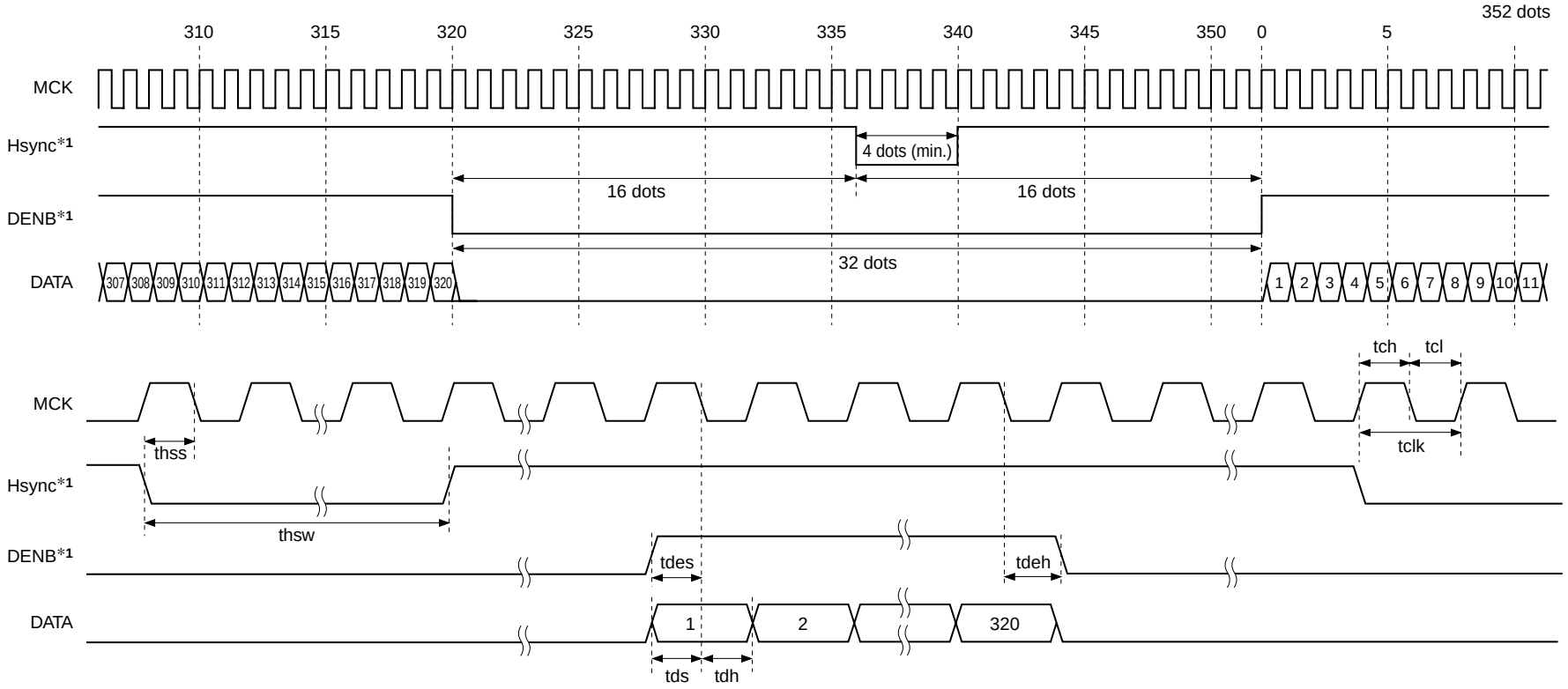
SLIN

This is a selector switch for sync input signal mode.

SLIN: Low → Hsync + Vsync Mode.

SLIN: High → DENB ONLY Mode. (Vsync is invalid.)

Horizontal Direction Input Signal Timing Chart

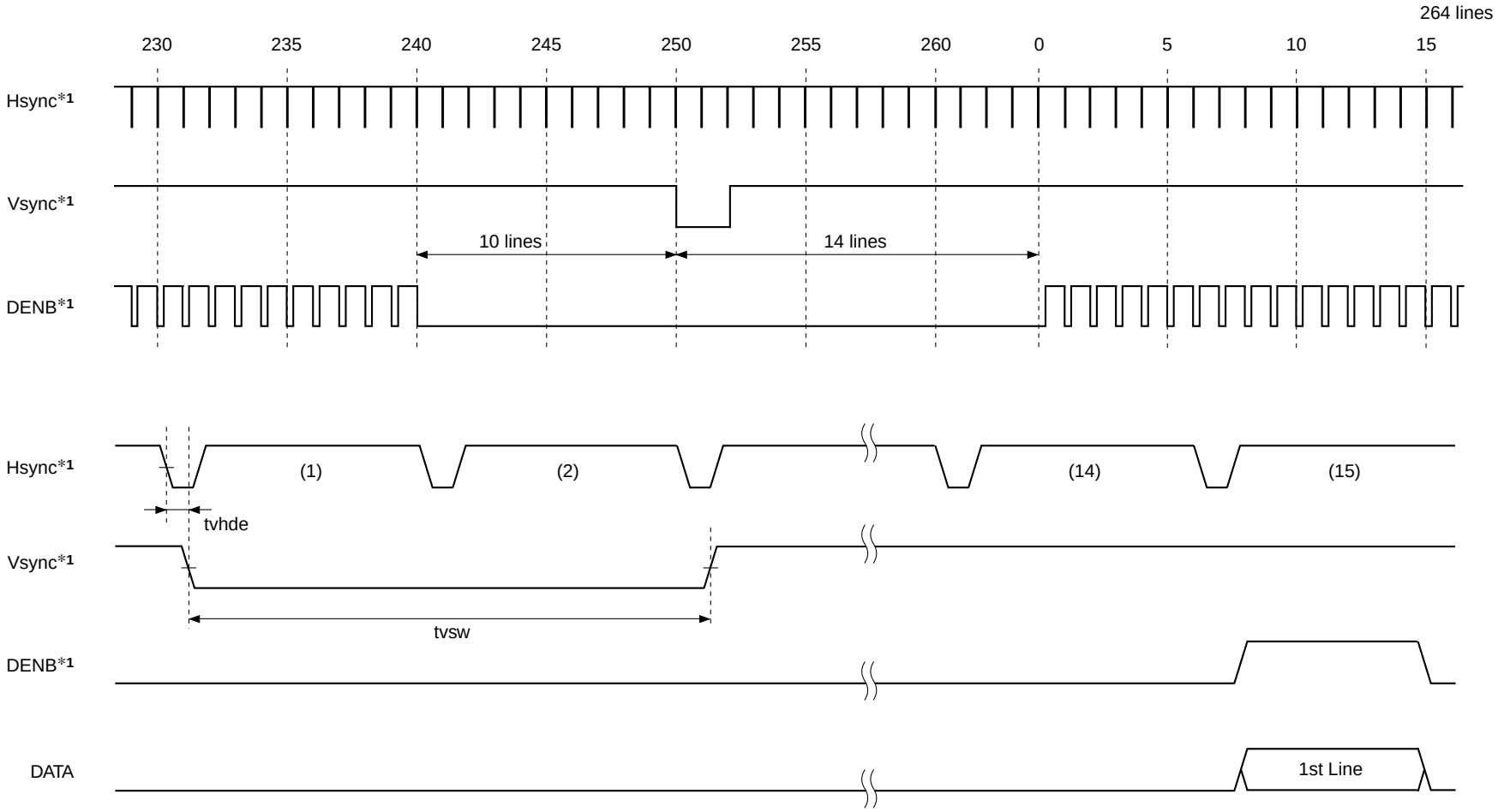


*1 Input either Hsync + Vsync or DENB as sync input signal.

Input Signal AC Characteristics (V_{DD1} = 3.0 to 3.6V, Ta = –25 to +75°C)

Item	Symbol	Min.	Typ.	Max.
MCK frequency	ftch	3MHz	5.58MHz	8MHz
MCK low, high pulse width	tch, tcl	—	0.5tclk	—
DATA setup time	tds	10ns	—	—
DATA hold time	tdh	15ns	—	—
DENB setup time	tdes	10ns	—	—
DENB hold time	tdeh	15ns	—	—
Hsync setup time	thss	10ns	—	—
Hsync low pulse width	thsw	4tclk	—	16tclk

Vertical Direction Input Signal Timing Chart

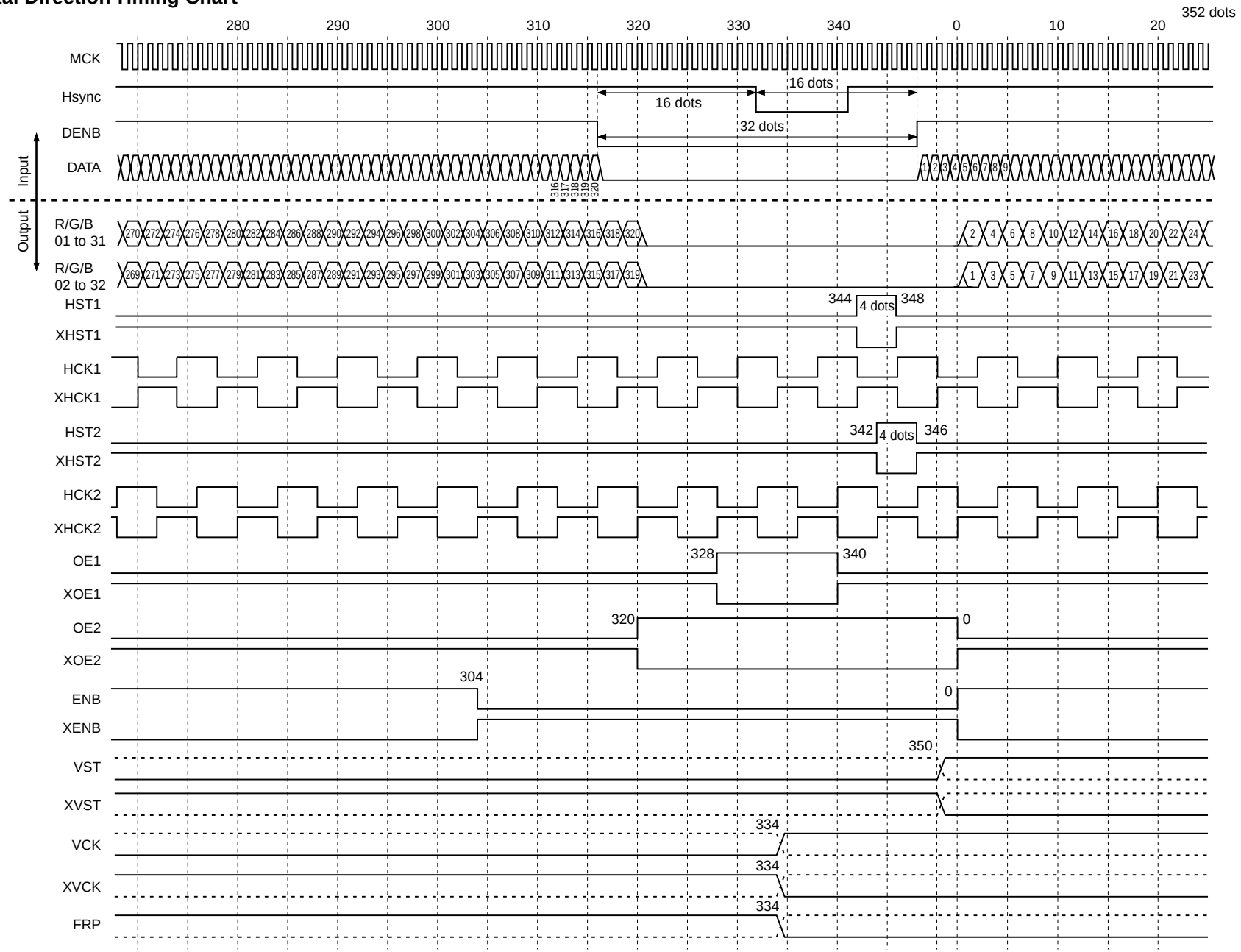


*1 Input either Hsync + Vsync or DENB as sync input signal.

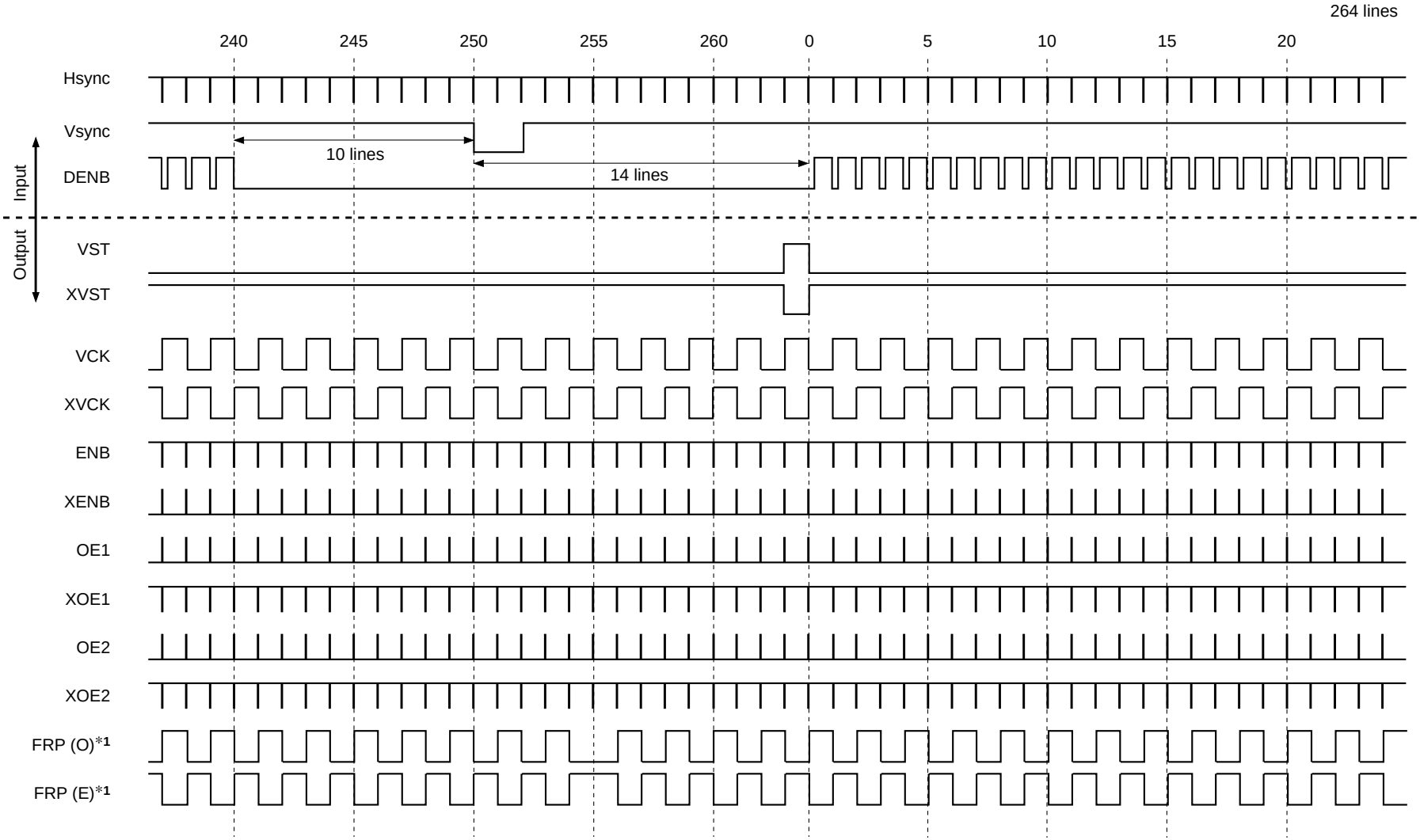
Input Signal AC Characteristics (V_{DD1} = 3.0 to 3.6V, Ta = –25 to +75°C)

Item	Symbol	Min.	Typ.	Max.
Hsync falling edge → Vsync falling edge	tvhde	3tclk	—	352tclk
Vsync low pulse width	tvsw	2 lines	—	14 lines

Horizontal Direction Timing Chart



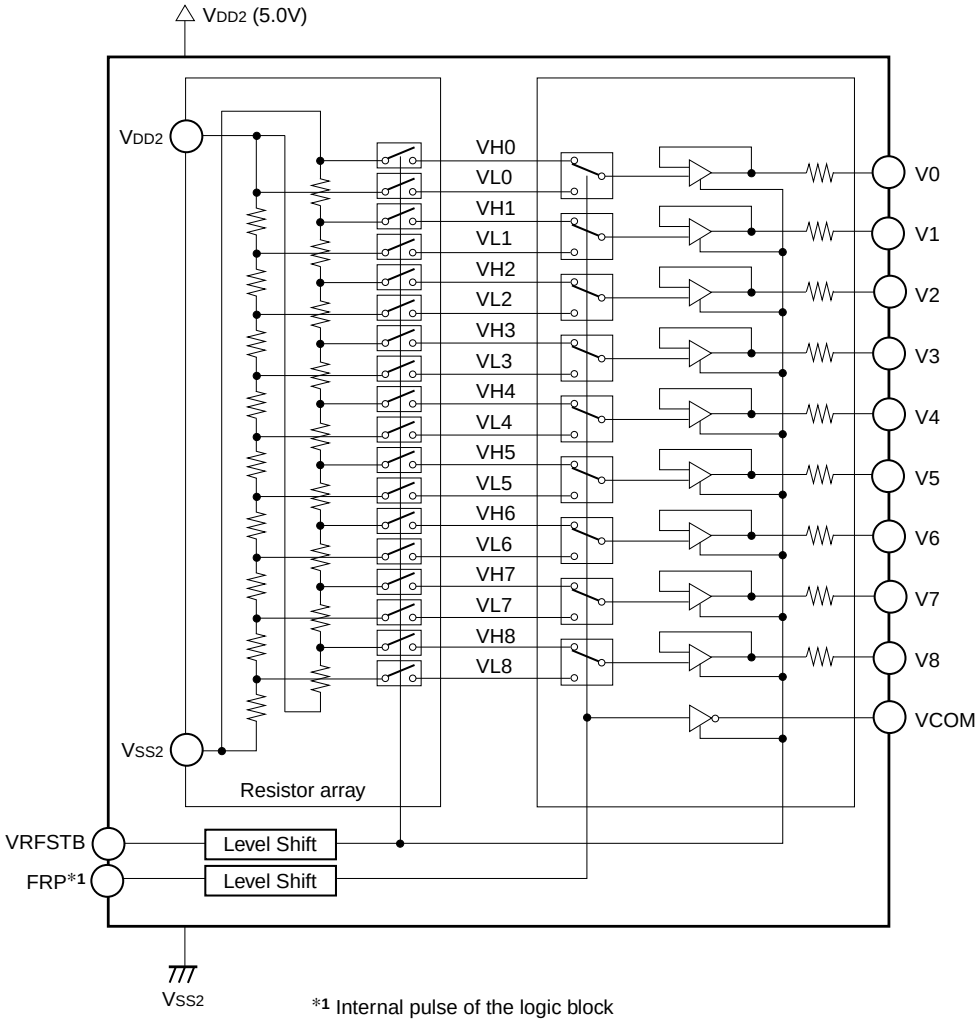
Vertical Direction Timing Chart



*1 FRP (O): FRP pulse at odd field. FRP (E): FRP pulse at even field.

Reference Voltage Driver Block

Block Diagram



*1 Internal pulse of the logic block

Electrical Characteristics (Reference voltage driver block)

Resistor array output voltage (V_{DD1} = 3.3V, V_{DD2} = 5.0V, Ta = 25°C)

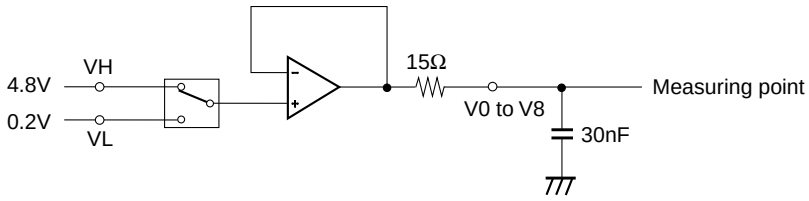
Item	Min.	Typ.	Max.	Unit	Item	Min.	Typ.	Max.	Unit
VH0	—	4.800	—	V	VL0	—	0.200	—	V
VH1	—	3.900	—		VL1	—	1.100	—	
VH2	—	3.325	—		VL2	—	1.675	—	
VH3	—	2.950	—		VL3	—	2.050	—	
VH4	—	2.600	—		VL4	—	2.400	—	
VH5	—	2.250	—		VL5	—	2.750	—	
VH6	—	1.950	—		VL6	—	3.050	—	
VH7	—	1.500	—		VL7	—	3.500	—	
VH8	—	0.500	—		VL8	—	4.500	—	

AC, DC Characteristics (V_{DD1} = 3.3V, V_{DD2} = 5.0V, Ta = –25 to +75°C)

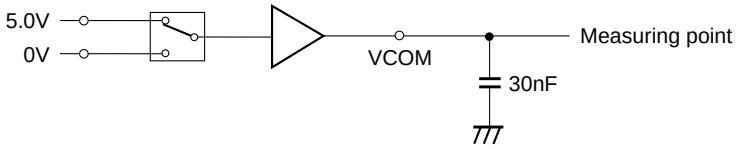
Item	Symbol	Conditions	Min.	Typ.	Max.	Unit
Supply voltage	V_{DD2}	—	4.7	5.0	5.3	V
Current consumption	I_{DD2}	Input voltage = 2.5V, During no load	—	3.4	6.0	mA
VH, VL input current high	I_{IH}	Input voltage = 4.8V	–0.15	—	0.15	µA
VH, VL input current low	I_{IL}	Input voltage = 0.2V	–0.15	—	0.15	µA
Voltage gain	AV	Input voltage = 0.2 to 4.8V	0.985	—	—	V/V
Output voltage high	V_{OH}	I_{SOURCE} = 10mA	V_{DD2} – 1.0	—	—	V
Output voltage low	V_{OL}	I_{SINK} = 10mA	—	—	GND + 1.0	V
COM output voltage high	V_{COH}	I_{SOURCE} = 10mA	V_{DD2} – 0.1	—	—	V
COM output voltage low	V_{COL}	I_{SINK} = 10mA	—	—	GND + 0.1	V
Offset voltage	V_{OFF}	Rs = 10kΩ	—	—	20	mV
Load regulation	ΔV_O	Input voltage = 0.2 to 4.8V I_{SOURCE} = 10mA I_{SINK} = 10mA	—	±5	±10	mV
Output impedance	R_{IMP}	V0 to V8	—	15	—	Ω
Settling time 1	ts_1	Measurement circuit 1	—	—	10	µs
Settling time 2	ts_2	Measurement circuit 1	—	—	10	µs
Settling time 3	ts_3	Measurement circuit 2	—	—	6	µs
Settling time 4	ts_4	Measurement circuit 2	—	—	6	µs

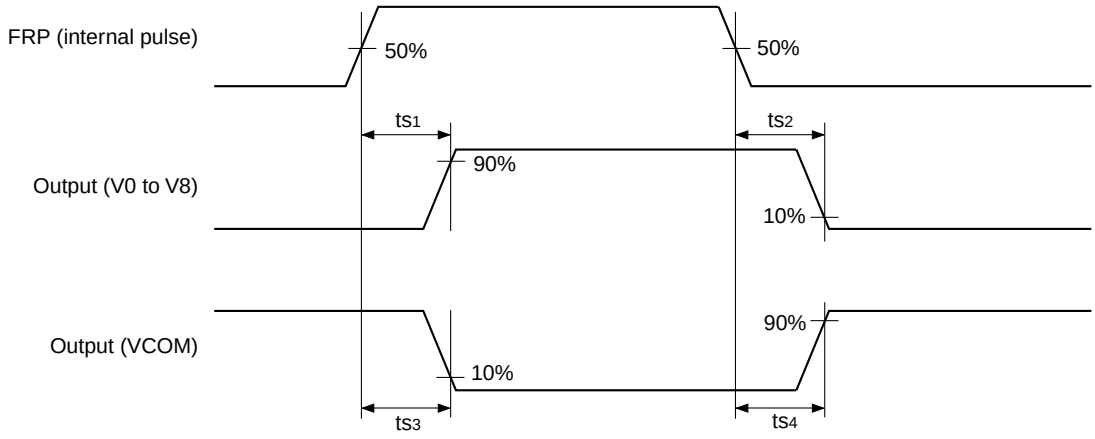
Measurement Circuit

Measurement circuit 1



Measurement circuit 2





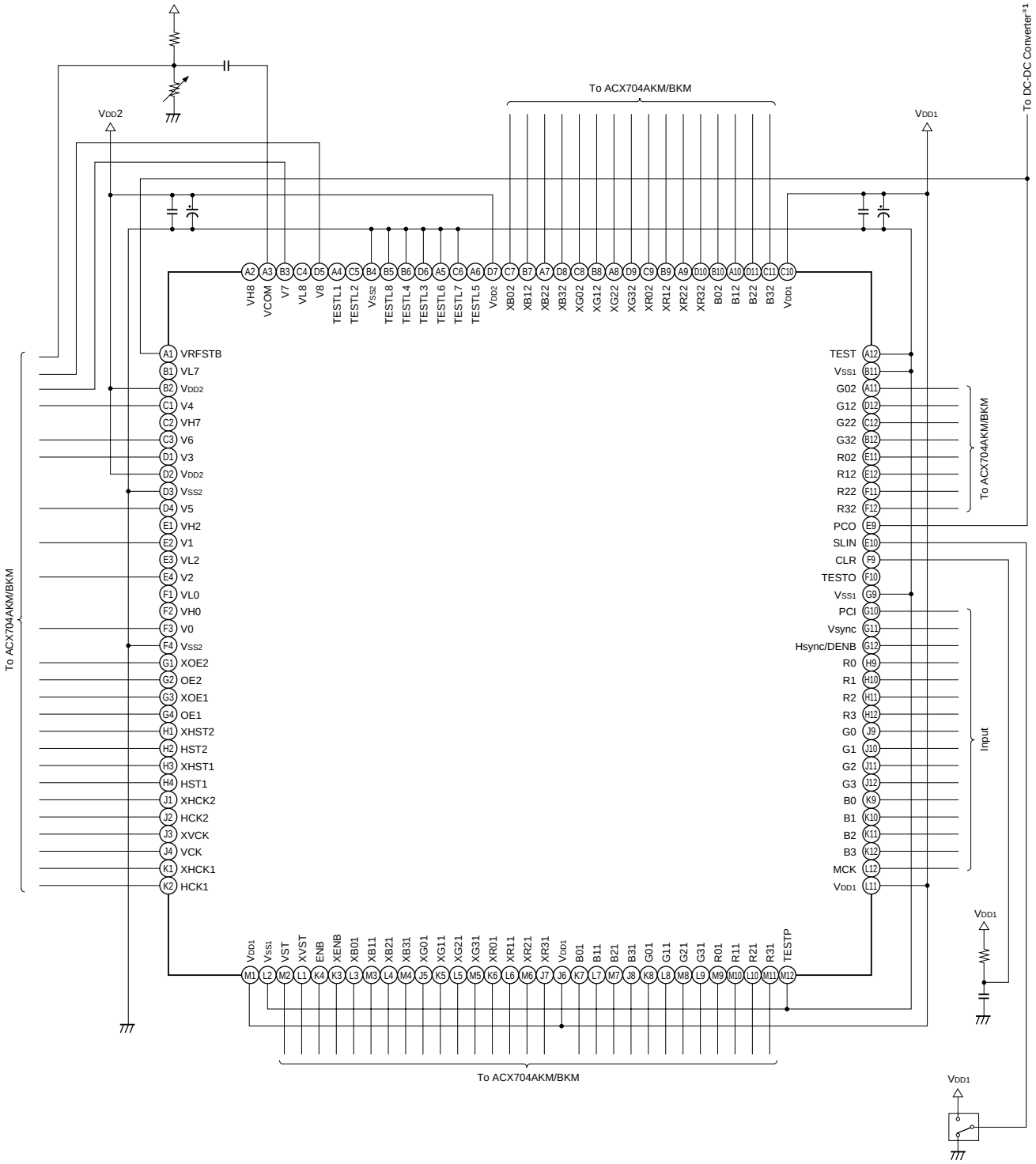
VRFSTB

This is a selector switch for reference voltage driver output on/off.

VRFSTB: Low → V0 to V8 and VCOM are GND level.

VRFSTB: High → V0 to V8 and VCOM are active.

Application Circuit

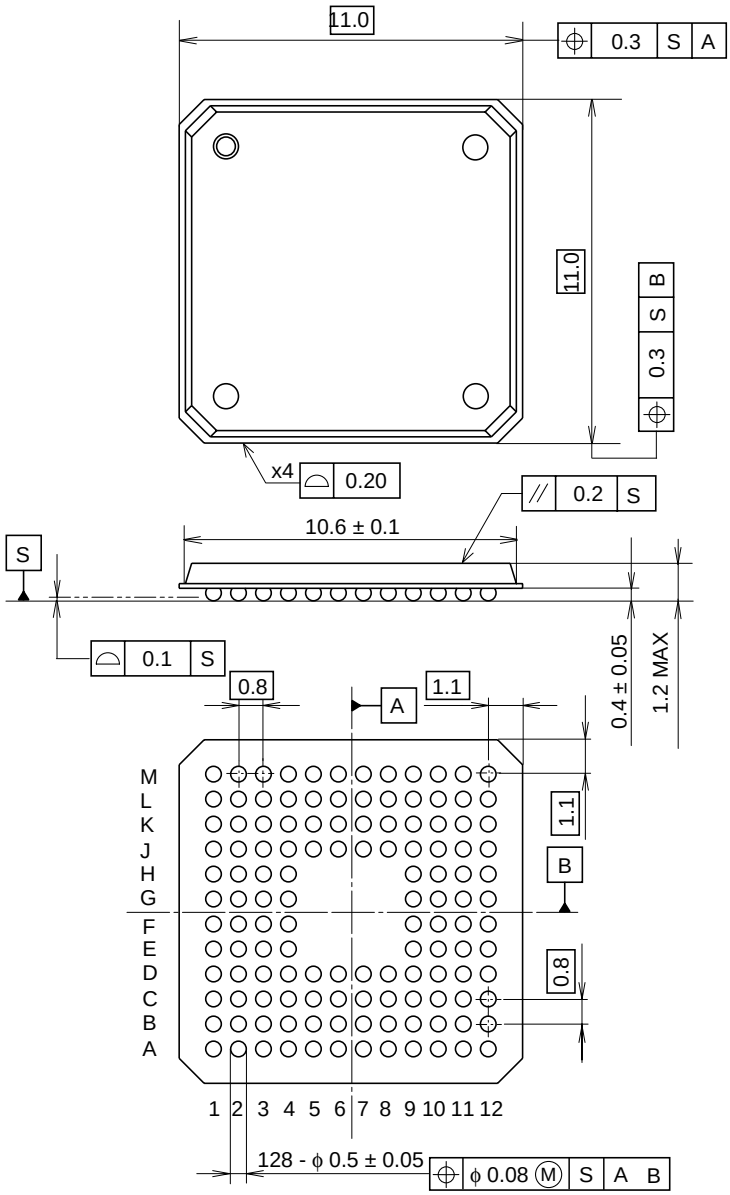


*1 Connect PCO to DC-DC converter that can control power on/off of the ACX704AKM/BKM.

Application circuits shown are typical examples illustrating the operation of the devices. Sony cannot assume responsibility for any problems arising out of the use of these circuits or for any infringement of third party patent and other right due to same.

Package Outline Unit: mm

128PIN TFBGA (PLASTIC)



PACKAGE STRUCTURE

PACKAGE MATERIAL	ORGANIC SUBSTRATE
TERMINAL TREATMENT	————
TERMINAL MATERIAL	SOLDER
PACKAGE MASS	0.22g

SONY CODE	TFBGA-128P-061
EIAJ CODE	P-TFBGA128-11x11-0.8
JEDEC CODE	————